WS3130 High Performance LED Driver

Features

- Single stage PFC
- Primary side regulation without Secondary Feedback
- Quasi Resonance (QR) mode with Confidential
- Fly-back topology
- Real-Current control to meet accurate output current
- Very less components
- Programmable input AV voltage compensation
- Leading Edge Blanking on CS/FB pin
- Protection Features
- Building in hysteresis OTP
- VDD over voltage protection
- Cycle by cycle current limiting on CS pin
- Secondary peak current protection on CS pin
- Output short to GND protection
- Output programmable over voltage protection
- FB and CS pins default protection

Applications

- LED lighting
- Down light
- Tube lamp
- PAR lamp
- Bulb

General Description

The WS3130 is a single-power stage, isolated and primary side offline LED lighting regulator which achieves high power factor.

The proprietary real-current control method can control the LED current accurately from the primary side information.

It can significantly simplify the LED lighting system design by eliminating the secondary side feedback components and the opto-coupler.

The WS3130 integrates active power factor correction and works in Quasi Resonance mode (QRM) in order to reduce the MOSFET switching losses.

With a building in 700V start-up MOSFET, IC can eliminate the power loss caused by start-up resistors to provide a high efficiency solution for lighting applications.

The external programmable line voltage compensation provides a more precise output current throughout the universal AC input voltage range.

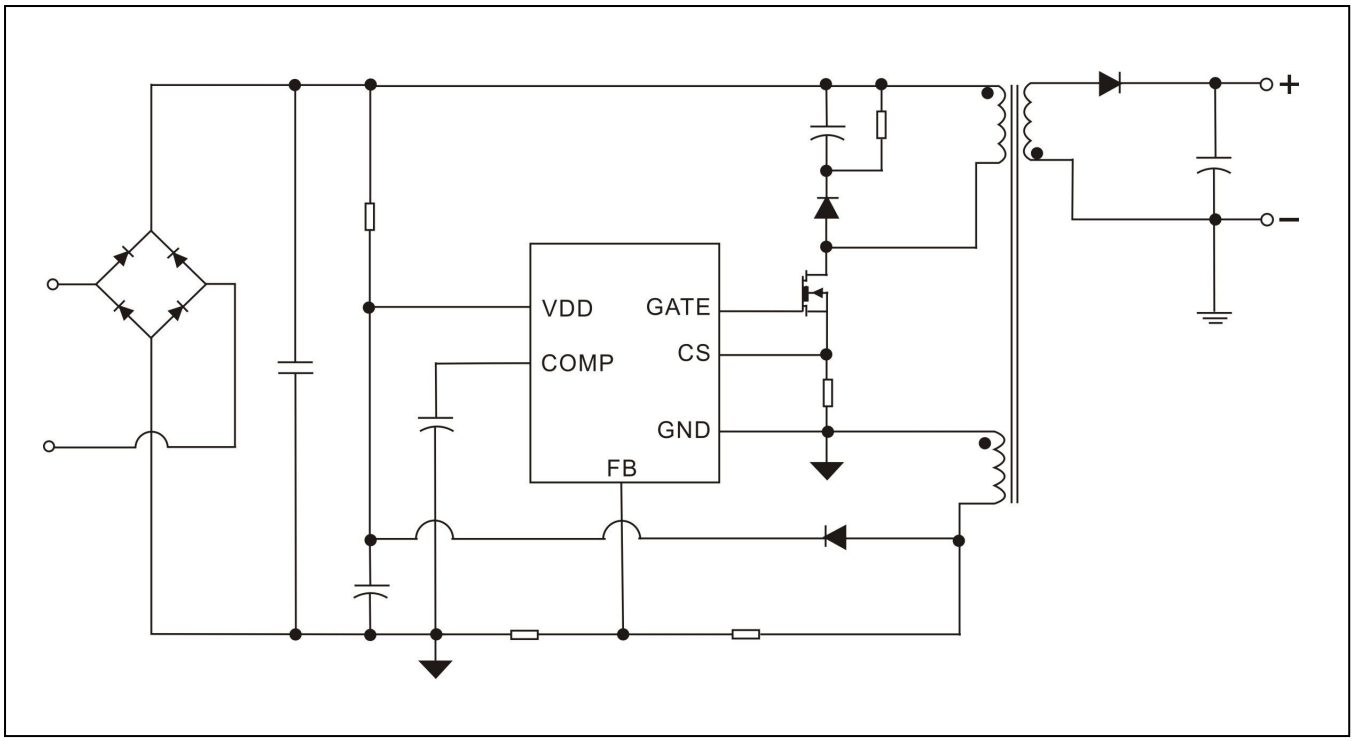
The leading edge blanking circuit on the CS/FB input removes the signal glitch and results in reduced external components and system cost. The multi-protection features of WS3130

Greatly enhance the system reliability and safety. Features VDD and output over voltage protection; output short circuit protection cycle-by-cycle current limit and secondary peak current protection on CS pin, VDD UVLO and auto-restart and over-temperature protection. The driver output voltage is clamped at 18V to protect the external power MOSFET.

WS3130 is offered in SOP-8 packages.

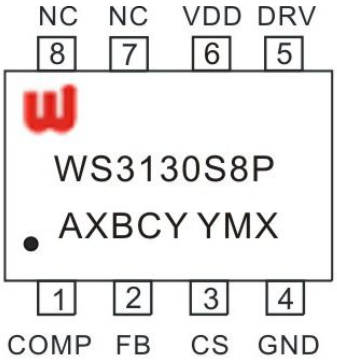
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Typical Application Circuit



Pin Definition and Device Marking

WS3130 is offered in SOP-8 packages，as shown below：

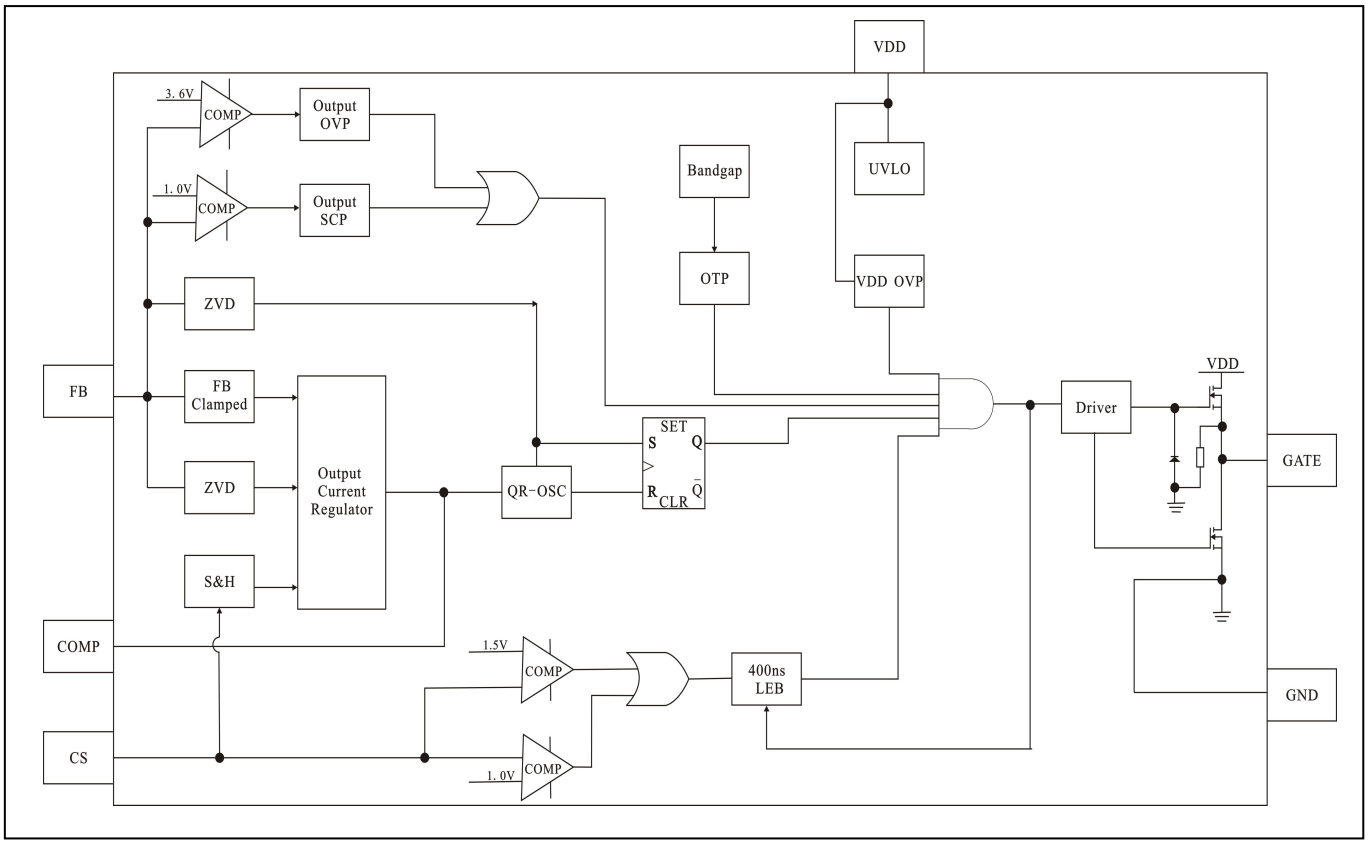


WS3130S8P
A：Product Code
X：Internal Code
BCY：Internal Code For QC
YMX：D/C

Pin Function Description

Pin Name	Pin No. DIP8/SOP8	Pin Type	Function Description
COMP	1	I	Loop compensation for constant current regulation.Output of the OTA.The RC work is placed between it and GND.
FB	2	I/O	Detect output diode zero current to regulate output current.connect to a resistor divider for sensing the reflected voltage from auxiliarywinding
CS	3	I	Current sense pin, a resistor connects to sense the MOSFET current.
GND	4	POWER	Power Ground
DRV	5	O	Totem-pole output to drive the external power MOSFET Maximum Voltage is internally clamped to 18V.
VDD	6	POWER	Power supply
NC	7/8	/	NO connect

Block Diagram



Ordering Information

Package	IC Marking Information	Purchasing Device Name
8-Pin SOP8, Pb-free	WS3130S8P	WS3130S8P

Recommended Operating Condition

Symbol	Parameter	Value	Unit
VCC	VCC Supply Voltage	10~28	V
T_A	Operating temperature	-20~85	℃

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CC}	VCC pin input voltage	28	V
V_{FB}	Feedback pin input voltage	-0.3~6	V
V_{CS}	Current sense pin input voltage	-0.3~6	V
V_{COMP}	Compensation pin voltage	-0.3~6	V
V_{DRV}	DRV pin input voltage	18	V
T_J	Operating junction temperature	150	℃
T_{STG}	Storage temperature range	-55~150	℃

Note 1: Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated in the Recommended Operating Conditions section are not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

ESD Information

Symbol	Parameter	Value	Unit
$V_{ESD-HBM}$	Human body model on all pins	2	KV
V_{ESD-MM}	Machine model on all pins	200	V

Electrical Characteristics(Unless otherwise specified，T_A=25℃，V_{CC}=15V)

Symbol	Parameter	Test Conditions	MIN	Typ.	MAX	Unit
VDD Pin						
I_{OP}	Operating Current	Gate Open		1		mA
VDD_{ON}	Turn-on Threshold Voltage			16		V
VDD_{OFF}	Turn-on Threshold Voltage			9		V
VDD_{OVP}	VDD Over Voltage Protection			25		V
CMP Pin						
V_{REF}	Reference voltage for OTA input			0.24		V
I_{CMP_SINK}	CMP maximal sink current			50		uA
I_{CMP_SOURCE}	CMP maximal source current			10		uA
V_{CMP_MAX}	CMP max. voltage			4.0		V
FB Pin						
V_{FB_SINK}	FB voltage when sink currentt	IFB_SINK=2mA		5.0		V
V_{FB_SOURCE}	FB voltage when source currentt	IFB_Source=4mA	-0.1	GND	+0.1	V
V_{FB_ZVD}	FB zero voltage detect			0.2		V
V_{FB_OVP}	FB voltage when output OVP			3.6		V
V_{FB_SCP}	FB voltage when trigger SCP			1.0		V
CS Pin						
V_{CS1}	Cycle by Cycle current limited on CS	FB=0V		1.0		V
T_{BLACK}	Leading-Edge Blanking Time		300	400	500	nS
Oscillator						
F_{OSC_MAX}	Maximal Frequency			130		KHZ
F_{OSC_MIN}	Minimal Frequency			30		KHZ
GATE Drive Output (GATE Pin)						
T_R	Rise Time	CL=1nF		200		nS
T_F	Fall Time	CL=1nF		100		nS
Over Temperature Protection						
OTP_H	Over Temperature Lockout			150		℃
OTP_L	Over Temperature Resume			125		℃

Operation

The WS3130 is a primary side control offline LED controller that incorporates all the features for performance LED lighting. LED current can be method form the primary side eliminate the unwanted harmonic noise injected onto the AC line.

Startup

During start-up, the current can charge up the VDD hold capacitor. the turn on and turn off threshold of WS3130 are approximately 15V and 9V respectively. The 6V hysteresis voltage is implemented to prevent shutdown from a voltage dip during start-up.

Quasi Resonance mode (QRM)

During the external power MOSFET on time (TON), the rectified input voltage is applied across the primary side inductor (Lm) and the primary current increases linearly from zero to the peak value (IPK).When the external power MOSFET turns off, the energy stored in the inductor forces the secondary side diode to be turn-on, and the current of the inductor begins to decrease linearly from the peak value to zero. When the current decreases to zero, the parasitic resonant of induct and all the parasitic capacitance makes the power MOSFET drain-source voltage decrease, this decreasing is also reflected on the auxiliary winding. The zero current detector in FB pin generates the turn on signal of the external MOSFET when the FB voltage is lower than 0.2V and ensures the MOSFET turn on at a valley voltage .As a result, there are virtually no primary switch turn-on losses and no secondary diode reverse-recover losses. It ensures high efficiency and low EMI noise.

Active Power Factor Correction(APFC)

WS3130 is designed with quasi-resonance and constant on time T_{on} to achieve high power factor under normal operation.The on time of WS3130 vary with input AC voltage $V_P Sin\varpi t$ and load condition and its value is constant basically because of very large loop compensaion capacitance on CMP pin.According to following equations,

$$I_{L-peak} = \frac{V_p Sin\varpi t}{L_m} \times T_{on} I_{L-avg} = \frac{V_p Sin\varpi t}{2 \times L_m} \times T_{on}^2 \times f_{osc}$$

The peak current I_{L-peak} and average current I_{L-avg} of transformer will be shaped as AC input sinusoid too beacause T_{on} and f_{osc} both are constant and then high power factor can be achieved.

Real Current Regulator without Secondary Feedback

The proprietary real current control method allows the WS3130 to accurately control the secondary side LED current from the primary side information.The output LED mean current can be calculated approximately as:

$$I_{OUT} = \frac{1}{2} \times \frac{V_{REF}}{R_{CS}} \times \frac{N_P}{N_S}$$

Where I_{OUT} is the secondary output current of LED, V_{REF} is the inner reference voltage. N_p is number of turns of primary winding and N_s is number of turns of the secondary winding.

Auto Starter

The WS3130 integrates an auto starter,the starter starts timing when the MOSFET is turned on,if FB fails to send out another turn on signal after 130 μ s,the starter will automatically send out the turn on signal which can avoid the IC unnecessary shut down by FB missing detecion.

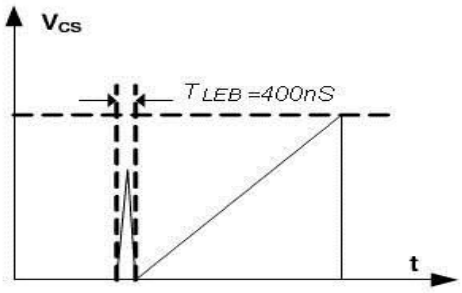
Minimal Off Time

The WS3130 operates with variable switching frequency. The frequency is changing with the input instantaneous line voltage. To limit the maximum frequency and get a good EMI performance, WS3130 employs an internal minimum off time limiter—3.5μs, show as figure.

Leading-Edge Blanking for CS pin

In order to avoid the premature termination of the switching pulse due to the parasitic capacitance discharging at MOSFET turning on,an internal leading edge blanking(LEB)

unit is employed between the CS Pin and the current comparator input.During the blanking time,the path,CS Pin to the current comparator input,is blocked.Figure shows the leading edge blanking.



Output over Voltage Protection

Output over voltage protection can prevent the components from damage in the over voltage condition.The positive plateau of auxiliary winding voltage is proportional to the output voltage. The OVP uses the auxiliary winding voltage instead of directly monitoring the output voltage. Once the FB pin voltage is higher than 3.6V, the OVP signal will be triggered and latched, the gate driver will be turned off and the IC work at quiescent mode, the VDD voltage dropped below the UVLO which will make the IC shut down and the system restarts again.The output OVP setting point can be calculated as:

$$V_{OUT_OVP} \approx 3.6 \times \frac{N_s}{N_{AUX}} \times \frac{R_{FBH} + R_{FBL}}{R_{FBL}}$$

V_{OUT_OVP} ……Output over voltge protection value

N_{AUX} ……the auxiliary winding turns

N_s ……the secondary winding turns

Current Limit

The current limit circuit senses the current of inductor by CS pin. When this current exceeds the internal threshold, typical is 1.0V, the power MOSFET is turned off for the remainder of that cycle.

Leading-Edge Blanking For FB Pin

As shown in Fig, when the power MOSFET is turned off, a damping voltage spike will occur at FB pin due to parasitic capacitance of power MOSFET and leak inductor of transformer. An internal leading edge blanking (LEB) was introduced to filter this noise.

Output Short Circuit Protection

When the output short circuit happens, the positive plateau of auxiliary winding voltage is also near zero. The IC will shut down and restart again once FB voltage falls below 1.0V and lasts for about 20mS.

Thermal Shut Down

The thermal shutdown circuitry senses the die temperature.The threshold is set at 150℃ typical with a 25℃ hysteresis.When the die temperature rises above this threshold (150℃),the 840X turn off the power MOSFET by DRV and remains turning off until the die temperature falls by 25℃,at which point it is re-enabled.

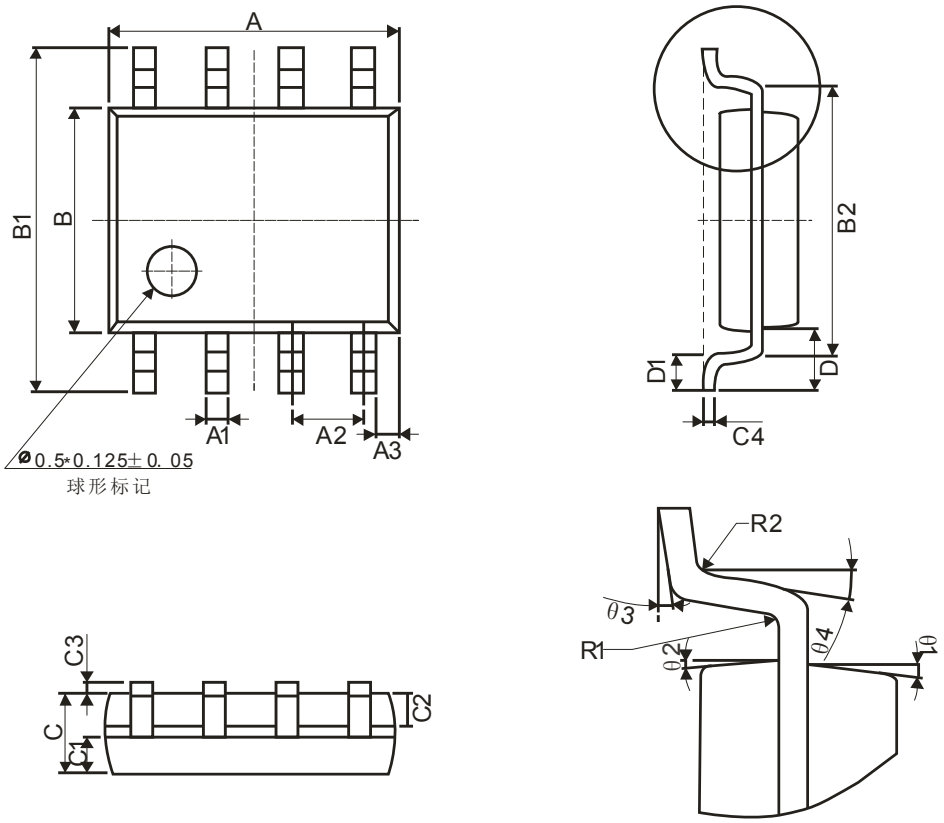
VDD over Voltage Protection

WS3130 provides an over voltage protection circuit for VDD pin. The GATE output will shut down once the VDD voltage exceeds 25V (typical value), the IC would restart until VDD drops to 9.0V.

Fault protection

There is several default protections were integrated in the WS3130 to prevent the IC from being damaged which including FB pin open or short, CS pin open.

SOP-8 Package Information



	Winsemi			
Symbol	**Dimensions in Millimeters**		**Dimensions in Inches**	
	Min	**Max**	**Min**	**Max**
A	4.70	5.10	0.185	0.201
B	3.70	4.10	0.146	0.161
C	1.30	1.50	0.051	0.059
A1	0.35	0.48	0.014	0.019
A2	1.27TYP		0.05TYP	
A3	0.345TYP		0.014TYP	
B1	5.80	6.20	0.228	0.244
B2	5.00TYP		0.197TYP	
C1	0.55	0.70	0.022	0.028
C2	0.55	0.70	0.022	0.028
C3	0.05	0.225	0.002	0.009
C4	0.203TYP		0.008TYP	
D	1.05TYP		0.041TYP	
D1	0.40	0.80	0.016	0.031

NOTE:

1.We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.

2.Please do not exceed the absolute maximum ratings of the device when circuit designing.

3.Winsemi Microelectronics Co., Ltd reserved the right to make changes in this specification sheet and is subject to change without prior notice.

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